

RJK0703DPN-E0

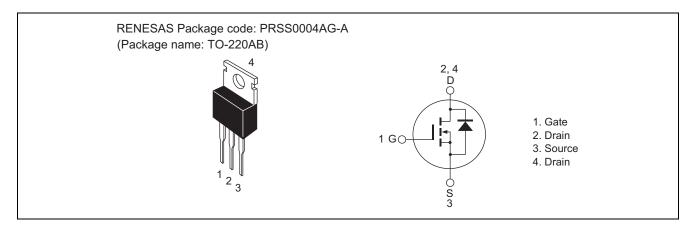
N-Channel MOS FET 75 V, 70 A, 6.7 m Ω

R07DS0624EJ0200 Rev.2.00 Aug 24, 2012

Features

- High speed switching
- Low drive current
- Low on-resistance $R_{DS(on)} = 5.3 \text{ m}\Omega \text{ typ.}$ (at $V_{GS} = 10 \text{ V}$)
- Package TO-220AB

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Ratings | Unit |
|--|------------------------------|-------------|------|
| Drain to source voltage | V _{DSS} | 75 | V |
| Gate to source voltage | V_{GSS} | ±20 | V |
| Drain current | I _D | 70 | Α |
| Drain peak current | I _{D (pulse)} Note1 | 210 | Α |
| Body-drain diode reverse drain current | I _{DR} | 70 | Α |
| Avalanche current | I _{AP} Note2 | 35 | Α |
| Avalanche energy | E _{AS} Note2 | 184 | mJ |
| Channel dissipation | Pch Note3 | 125 | W |
| Channel to case thermal impedance | θch-c | 1.0 | °C/W |
| Channel temperature | Tch | 150 | °C |
| Storage temperature | Tstg | -55 to +150 | °C |

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at L = 100 μH , Tch = 25°C, Rg $\geq 50\Omega,$
- 3. Tc = 25°C

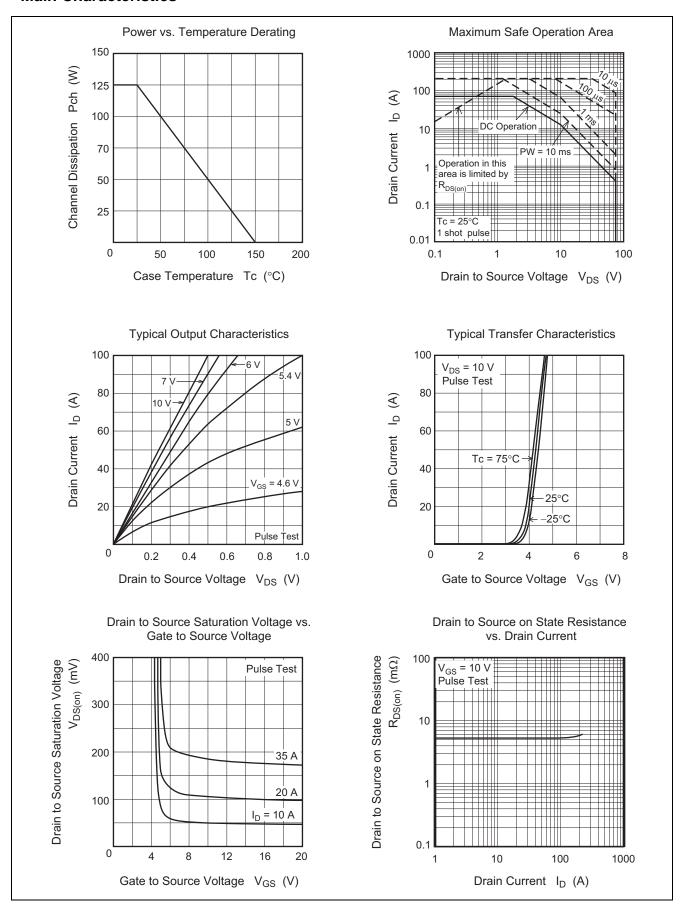
Electrical Characteristics

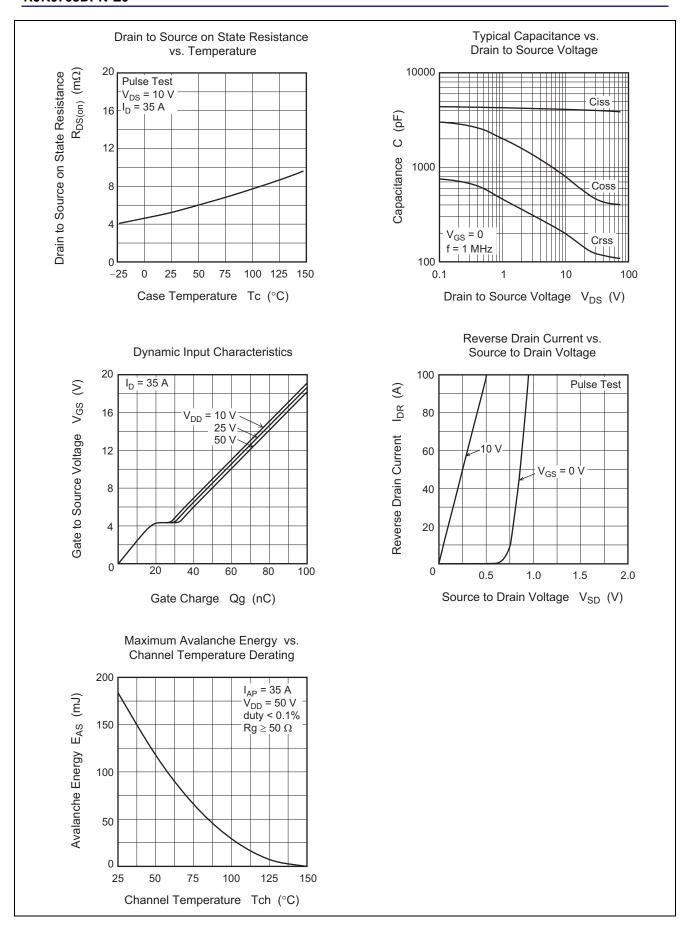
 $(Ta = 25^{\circ}C)$

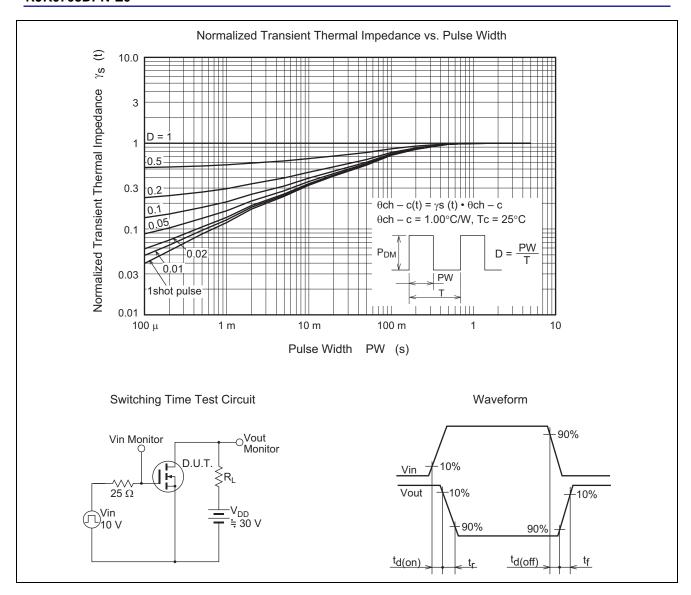
| Item | Symbol | Min | Тур | Max | Unit | Test conditions |
|--|---------------------|-----|------|------|------|--|
| Drain to source breakdown voltage | $V_{(BR)DSS}$ | 75 | _ | _ | V | $I_D = 10 \text{mA}, V_{GS} = 0$ |
| Gate to source leak current | I_{GSS} | _ | _ | ±0.1 | μΑ | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$ |
| Zero gate voltage drain current | I _{DSS} | _ | _ | 1 | μΑ | $V_{DS} = 75 \text{ V}, V_{GS} = 0$ |
| Gate to source cutoff voltage | $V_{GS(off)}$ | 2.0 | _ | 4.0 | V | $V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$ |
| Static drain to source on state | R _{DS(on)} | | 5.3 | 6.7 | mΩ | $I_D = 35 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$ |
| resistance | | | | | | |
| Forward transfer admittance | y _{fs} | | 90 | _ | S | $I_D = 35 \text{ A}, V_D = 10 \text{ V}^{\text{Note4}}$ |
| Input capacitance | Ciss | | 4150 | _ | pF | V _{DS} = 10 V |
| Output capacitance | Coss | _ | 830 | _ | pF | V _{GS} = 0 f = 1 MHz |
| Reverse transfer capacitance | Crss | _ | 200 | _ | рF | |
| Gate Resistance | Rg | _ | 1.6 | _ | Ω | |
| Total gate charge | Qg | _ | 56 | _ | nC | V _{DD} = 25 V |
| Gate to source charge | Qgs | _ | 20 | _ | nC | $V_{GS} = 10 \text{ V},$ $I_D = 35 \text{ A}$ |
| Gate to drain charge | Qgd | _ | 8 | _ | nC | |
| Turn-on delay time | t _{d(on)} | | 30 | _ | ns | V _{GS} = 10 V |
| Rise time | t _r | | 10 | _ | ns | $\begin{split} I_D &= 35 \text{ A} \\ V_{DD} &\cong 30 \text{ V} \\ Rg &= 4.7 \Omega \end{split}$ |
| Turn-off delay time | t _{d(off)} | | 60 | _ | ns | |
| Fall time | t _f | _ | 11 | _ | ns | |
| Body-drain diode forward voltage | V_{DF} | _ | 0.85 | 1.5 | V | $I_F = 70 \text{ A}, V_{GS} = 0^{\text{Note4}}$ |
| Body-drain diode reverse recovery time | t _{rr} | _ | 50 | _ | ns | $I_F = 70 \text{ A}, V_{GS} = 0$ |
| | | | | | | $di_F/dt = 100 A/\mu s$ |

Notes: 4. Pulse test

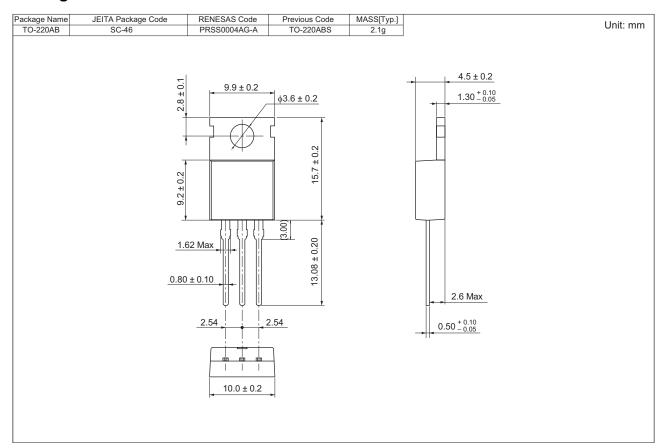
Main Characteristics







Package Dimensions



Ordering Information

| Orderable Part Number | Quantity | Shipping Container |
|-----------------------|----------|--------------------|
| RJK0703DPN-E0-T2 | 50 pcs | Magazine (Tube) |

Note: The symbol of 2nd "-" is occasionally presented as "#".

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